

### FAST SWITCHING DIODE 1N914B

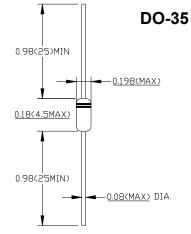
# VOLTAGE RANGE75 VoltsForward Current0.15 Amperes

#### FEATURES

- Extrem fast switching
- Low cost

#### MECHANICAL DATA

- Case: Glass sealed envelope
- Polarity: Color band denotes cathode end
- Lead: Plated axial lead, solderable per MIL-STD-202E Method 208C
- Mounting Position: Any
- Weight: 0.012 ounce, 0.33gram



Dimensions in inches and (millimeters)

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load derate current by 20%.

		SYMBOLS	1N914B	UNITS
Maximum Repetitive Peak Reverse Voltage		V <sub>RRM</sub>	100	Volts
Maximum DC Blocking Voltage		V <sub>DC</sub>	75	Volts
Maximum Average Forward Rectified Current 0 375" (9 5mm) lead length at $T_A=25$		I <sub>(AV)</sub>	150	mAmps
Peak Forward Surge Current 8 3ms single half sine-wave superimposed on rated load (JEDEC Method)		I <sub>FSM</sub>	400	mAmps
Maximum Instantaneous Forward Voltage Drop at 100mA		$V_{\rm F}$	1 0	Volts
rated DC blocking voltage at	V <sub>A</sub> =25 ,V <sub>R</sub> =75V V <sub>A</sub> =150 ,V <sub>R</sub> =20V	I <sub>R</sub>	5 0 50	μΑ
Maximum Reverse Recovery Time (Note1)		t <sub>rr</sub>	4 0	nS
Typical Junction Capacitance (Note 2)		CJ	4 0	pF
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-65 to +200	°C

NOTES:

1. Test condition: I<sub>F</sub>=20mA,I<sub>R</sub>=mA,V<sub>R</sub>=6V,R<sub>L</sub>=100Ω

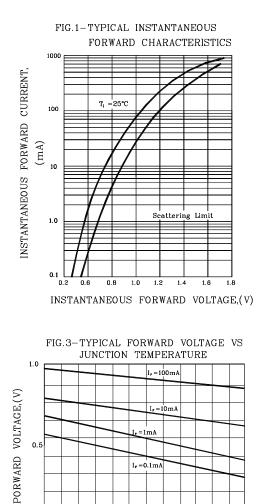
2. Measured at 1.0MHz and applied reverse voltage of 4.0volts.



1N914B

VOLTAGE RANGE75 VoltsForward Current0.15 Amperes

## **RATING AND CHARACTERISTIC CURVES 1N914B**



0 -20

20

0

40

JUNCTION TEMPERATURE, (°c)

60

80

100

